



ISB3015

eq BU941PFI

isc Silicon NPN Power Transistor

DESCRIPTION

- Collector-Emitter Breakdown Voltage
 $-V_{(BR)CEO} = 400V(\text{Min})$

APPLICATIONS

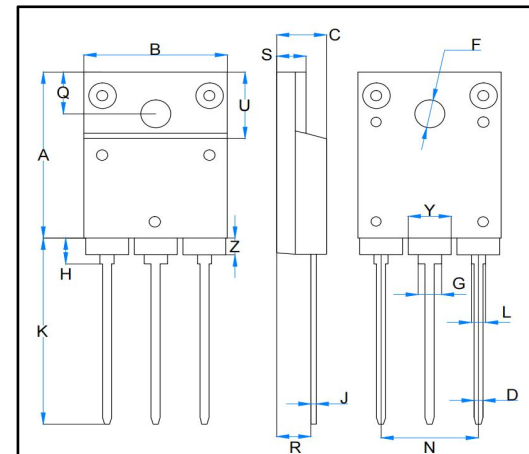
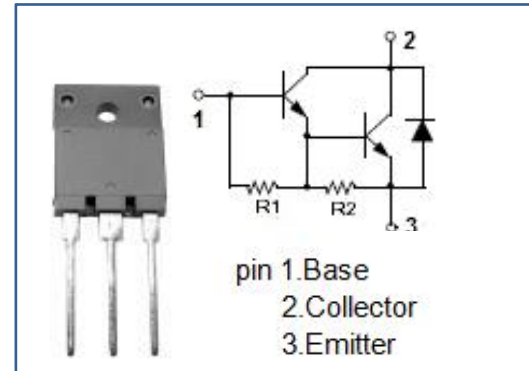
- Designed for power amplifier
- high speed switching and regulated power supply applications.

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CEO}	Collector-Emitter Voltage	400	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current-Continuous	15	A
I_{CM}	Collector Peak Current	30	A
I_B	Base Current-Continuous	1	A
P_C	Collector Power Dissipation	65	W
T_J	Junction Temperature	175	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~175	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	2.3	$^\circ\text{C}/\text{W}$



DIM	mm		
	MIN	TYP.	MAX
A	19.90	20.00	20.10
B	15.90	16.00	16.10
C	5.50	5.60	5.70
D	0.90	1.00	1.10
F	3.30	3.40	3.50
G	2.90	3.00	3.10
H	5.90	6.00	6.10
J	0.50	0.60	0.70
K	22.30	22.40	22.50
L	1.90	2.00	2.10
N	10.80	10.90	11.00
Q	4.90	5.00	5.10
R	3.75	3.85	3.95
S	3.20	3.30	3.40
U	7.90	8.00	8.10
Y	4.70	4.80	4.90
Z	1.90	2.00	2.10



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ELECTRICAL CHARACTERISTICS (T_C=25°C unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{CEO}	Collector-Emitter Breakdown Voltage	I _C =100mA; I _B = 0	400	--	V
I _{CEO}	Collector Cut offCurrent	V _{CB} = 450V; I _E = 0	--	100	uA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0	--	20	mA
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 8A; I _B =0.1A	--	1.6	V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10A; I _B =0.25A	--	1.8	V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C =12A; I _B =0.3A	--	2.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C =8A; I _B =0.1A	--	2.2	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C =10A; I _B =0.25A	--	2.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 12A; I _B =0.3A	--	2.7	V
h _{FE}	DC Current Gain	I _C = 5A; V _{CE} = 10V	300		
V _F	Diode Forward Voltage	I _F = 10 A		2.5	V

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